U.S. Departm	ent of Co	mmerce, Patent and	l Trademark Offi	ce	Atty Dock	tet No.	Serial N	0	
						M-12589 US		10/080,468	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT					Applicant(s)				
(Use several sheets if necessary)						Hua Ji			
						Filing Date			
					February 22, 2002		Group Unknown		
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